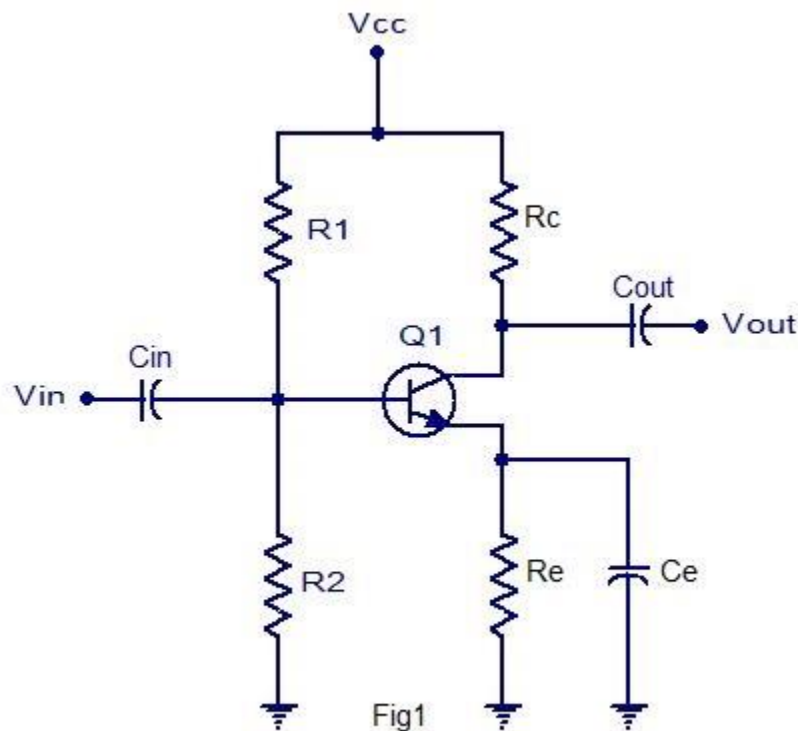


COMMON EMITTER RC COUPLED AMPLIFIER

The common emitter RC coupled amplifier is one of the simplest and elementary transistor amplifier that can be made. Don't expect much boom from this little circuit, the main purpose of this circuit is pre-amplification i.e to make weak signals strong enough for further processing or amplification. If designed properly, this amplifier can provide excellent signal characteristics. The circuit diagram of a single stage common emitter RC coupled amplifier using transistor is shown in Fig1.



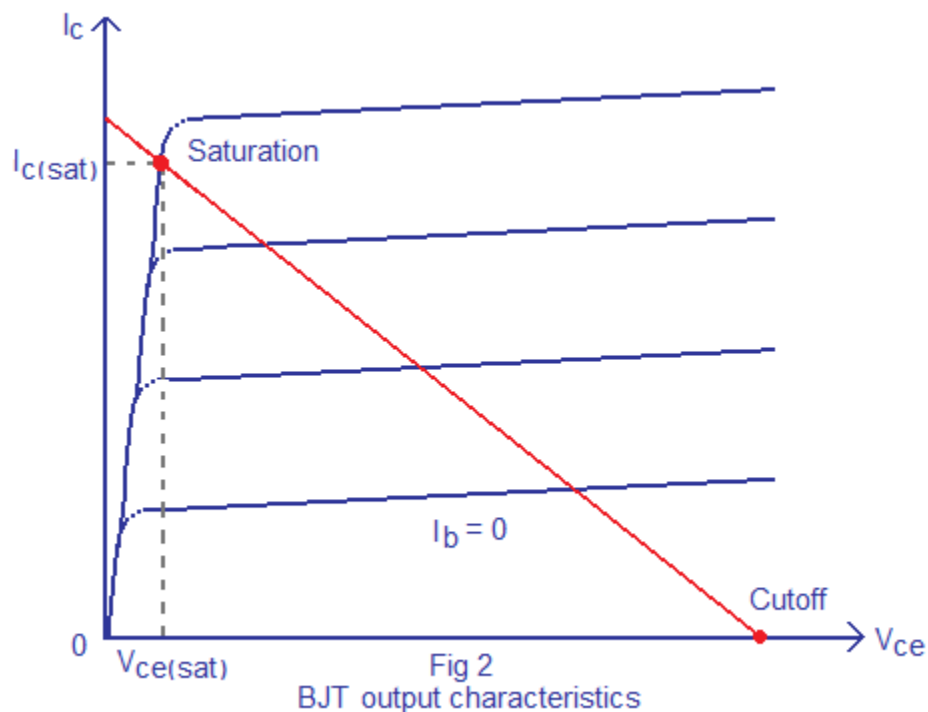
Comon emitter RC coupled amplifier

RC coupled amplifier

Capacitor C_{in} is the input DC decoupling capacitor which blocks any DC component if present in the input signal from reaching the Q_1 base. If any external DC voltage reaches the base of Q_1 , it will alter the biasing conditions and affects the performance of the amplifier.

R_1 and R_2 are the biasing resistors. This network provides the transistor Q_1 's base with the necessary bias voltage to drive it into the active region. The region of operation where the transistor is completely switched off is called cut-off region and the region of operation where the transistor is completely switched ON (like a closed switch) is called saturation region. The region in between cut-

off and saturation is called active region. Refer Fig 2 for better understanding. For a transistor amplifier to function properly, it should operate in the active region. Let us consider this simple situation where there is no biasing for the transistor. As we all know, a silicon transistor requires 0.7 volts for switch ON and surely this 0.7 V will be taken from the input audio signal by the transistor. So all parts of there input wave form with amplitude $\leq 0.7V$ will be absent in the output waveform. In the other hand if the transistor is given with a heavy bias at the base ,it will enter into saturation (fully ON) and behaves like a closed switch so that any further change in the base current due to the input audio signal will not cause any change in the output. The voltage across collector and emitter will be 0.2V at this condition ($V_{ce\ sat} = 0.2V$). That is why proper biasing is required for the proper operation of a transistor amplifier.



BJT output characteristics

C_{out} is the output DC decoupling capacitor. It prevents any DC voltage from entering into the succeeding stage from the present stage. If this capacitor is not used the output of the amplifier (V_{out}) will be clamped by the DC level present at the transistors collector.

R_c is the collector resistor and R_e is the emitter resistor. Values of R_c and R_e are so selected that 50% of V_{cc} gets dropped across the collector & emitter of the transistor. This is done to ensure that the operating point is positioned at the center of the load line. 40% of V_{cc} is dropped across R_c and 10%

of V_{cc} is dropped across R_e . A higher voltage drop across R_e will reduce the output voltage swing and so it is a common practice to keep the voltage drop across $R_e = 10\% V_{cc}$. C_e is the emitter bypass capacitor. At zero signal condition (i.e, no input) only the quiescent current (set by the biasing resistors R_1 and R_2 flows through the R_e). This current is a direct current of magnitude few milli amperes and C_e does nothing. When input signal is applied, the transistor amplifies it and as a result a corresponding alternating current flows through the R_e . The job of C_e is to bypass this alternating component of the emitter current. If C_e is not there, the entire emitter current will flow through R_e and that causes a large voltage drop across it. This voltage drop gets added to the V_{be} of the transistor and the bias settings will be altered. In reality, it is just like giving a heavy negative feedback and so it drastically reduces the gain.

Source : <http://todayscircuits.blogspot.com/2011/12/transistor-amplifier.html#.VUBxr9Kqqkp>